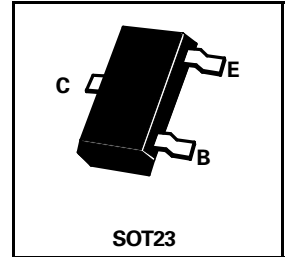


SOT23 NPN SILICON PLANAR GENERAL PURPOSE TRANSISTORS

ISSUE 6 - JANUARY 1997

BC846	BC847
BC848	BC849
BC850	

PARTMARKING DETAILS		COMPLEMENTARY TYPES	
BC846A-Z1A	BC848B-1K	BC846	BC856
BC846B-1B	BC848C-Z1L	BC847	BC857
BC847A-Z1E	BC849B-2B	BC848	BC858
BC847B-1F	BC849C-2C	BC849	BC859
BC847C-1GZ	BC850B-2FZ	BC850	BC860
BC848A-1JZ	BC850C-Z2G		



ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	BC846	BC847	BC848	BC849	BC850	UNIT
Collector-Base Voltage	V _{CBO}	80	50	30	30	50	V
Collector-Emitter Voltage	V _{CES}	80	50	30	30	50	V
Collector-Emitter Voltage	V _{CEO}	65	45	30	30	45	V
Emitter-Base Voltage	V _{EBO}	6		5			V
Continuous Collector Current	I _C	100					mA
Peak Collector Current	I _{CM}	200					mA
Peak Base Current	I _{BM}	200					mA
Peak Emitter Current	I _{EM}	200					mA
Power Dissipation at T _{amb} =25°C	P _{tot}	330					mW
Operating and Storage Temperature Range	T _j :T _{stg}	-55 to +150					°C

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ unless otherwise stated).

PARAMETER	SYMBOL	BC846	BC847	BC848	BC849	BC850	UNIT	CONDITIONS.
Collector Cut-Off Current	I_{CBO}	Max	15				nA	$V_{CB} = 30V$
		Max	5				μA	$V_{CB} = 30V$ $T_{amb}=150^{\circ}C$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	Typ	90				mV	$I_C=10mA$, $I_B=0.5mA$
		Max.	250				mV	$I_C=100mA$, $I_B=5mA$
		Typ	200				mV	$I_C=10mA$, $I_B=5mA$
		Max.	600				mV	$I_C=10mA$ *
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	Typ	700				mV	$I_C=10mA$, $I_B=0.5mA$
		Typ	900				mV	$I_C=100mA$, $I_B=5mA$
Base-Emitter Voltage	V_{BE}	Min	580				mV	$I_C=2mA$
		Typ	660				mV	$V_{CE}=5V$
		Max	700				mV	$I_C=10mA$
		Max	770				mV	$V_{CE}=5V$

* Collector-Emitter Saturation Voltage at $I_C = 10mA$ for the characteristics going through the operating point $I_C = 11mA$, $V_{CE} = 1V$ at constant base current.

BC846	BC847
BC848	BC849
BC850	

ELECTRICAL CHARACTERISTICS (Continued)

PARAMETER	SYMBOL		BC846	BC847	BC848	BC849	BC850	UNIT	CONDITIONS.
Static Forward Current Ratio	Group VI	h _{FE}	Min	75	75	75	—	—	I _C =2mA, V _{CE} =5V
			Typ	110	110	110	—	—	
			Max	150	150	150	—	—	
	Group A	h _{FE}	Typ	90	90	90	—	—	I _C =0.01mA, V _{CE} =5V
			Min	110	110	110	—	—	I _C =2mA, V _{CE} =5V
			Typ	180	180	180	—	—	
			Max	220	220	220	—	—	
	Group B	h _{FE}	Typ	120	120	120	—	—	I _C =100mA, V _{CE} =5V
			Typ	150					I _C =0.01mA, V _{CE} =5V
			Min	200					I _C =2mA, V _{CE} =5V
			Typ	290					
			Max	450					
		Typ	200	200	200	—	—	I _C =100mA, V _{CE} =5V	
Group C	h _{FE}	Typ.	—	270	270	270	270	I _C =0.01mA, V _{CE} =5V	
		Min	—	420	420	420	420	I _C =2mA, V _{CE} =5V	
		Typ	—	500	500	500	500		
		Max	—	800	800	800	800		
		Typ	—	—	400	—	—	I _C =100mA, V _{CE} =5V	
Transition Frequency	f _T	Typ	300					MHz	I _C =10mA, V _{CE} =5V f=100MHz
Collector-Base Capacitance	C _{obo}	Typ	2.5					pF	V _{CB} =10V f=1MHz
		Max	4.5						
Emitter-Base Capacitance	C _{ib0}	Typ	9					pF	V _{EB} =0.5V f=1MHz
Noise Figure	N	Typ	2	2	2	1.2	1	dB	V _{CE} = 5V, I _C =200μA, R _C =2kΩ, f=1kHz, Δf=200Hz
		Max	10	10	10	4	4		
		Typ	—	—	—	1.2	1	dB	V _{CE} = 5V, I _C =200μA, R _C =2kΩ, f=30Hz to 15kHz at -3dB points
		Max	—	—	—	4	3		
Equivalent Noise Voltage	e _n	Max.	—	—	—	110	110	nV	V _{CE} = 5V, I _C =200μA, R _C =2kΩ, f=10Hz to 50Hz at -3dB points

Spice parameter data is available upon request for this device

BC846	BC847
BC848	BC849
BC850	

ELECTRICAL CHARACTERISTICS (Continued)

PARAMETER		SYMBOL		BC846	BC847	BC848	BC849	BC850	UNIT	CONDITIONS.
Dynamic Characteristics	Group VI Group A Group B Group C	h _{ie}	Min	0.4	0.4	0.4	–	–	kΩ	V _{CE} =5V I _C =2mA
			Typ	1.2	1.2	1.2	–	–	kΩ	
			Max	2.2	2.2	2.2	–	–	kΩ	
			Min	1.6	1.6	1.6	–	–	kΩ	
			Typ	2.7	2.7	2.7	–	–	kΩ	
			Max	4.5	4.5	4.5	–	–	kΩ	
			Min	3.2					kΩ	
			Typ	4.5					kΩ	
			Max	8.5					kΩ	
			Min	–	–	6	6	6	kΩ	
Typ	–	–	8.7	8.7	8.7	kΩ				
Max	–	–	15	15	15	kΩ				
Group VI Group A Group B Group C	h _{re}	Typ	2.5	2.5	2.5	–	–	x10 ⁻⁴		
		Typ	1.5	1.5	1.5	–	–	x10 ⁻⁴		
		Typ	2	2	2	2	2	x10 ⁻⁴		
		Typ	–	–	3	3	3	x10 ⁻⁴		
Group VI Group A Group B Group C	h _{fe}	Min	75	75	75	–	–			
		Typ	110	110	110	–	–			
		Max	150	150	150	–	–			
		Min	125	125	125	–	–			
		Typ	220	220	220	–	–			
		Max	260	260	260	–	–			
		Min	240							
		Typ	330							
		Max	500							
		Min	–	450	450	450	450			
Typ	–	600	600	600	600					
Max	–	900	900	900	900					
Group VI Group A Group B Group C	h _{oe}	Typ	20	20	20	–	–	μs		
		Max	40	40	40	–	–	μs		
		Typ	18	18	18	–	–	μs		
		Max	30	30	30	–	–	μs		
		Typ	30					μs		
		Max	60					μs		
		Typ	–	–	60	60	60	μs		
		Max	–	–	110	110	110	μs		